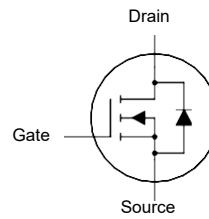


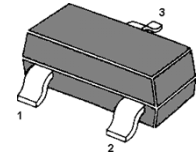
## MMBT7002-CAR N-Channel Enhancement Mode Field Effect Transistor

### Features

- High density cell design for low  $R_{DS(ON)}$
- Voltage controlled small signal switching
- High saturation current capability
- High speed switching
- Lead Free/RoHS Compliant
- Qualified to AEC-Q101 Standards for High Reliability



Equivalent Circuit



1. Gate 2. Source 3. Drain  
SOT-23 Plastic Package

MARKING:K702

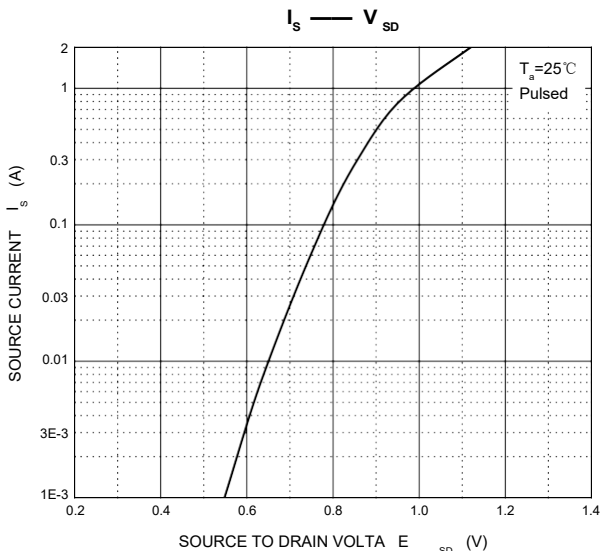
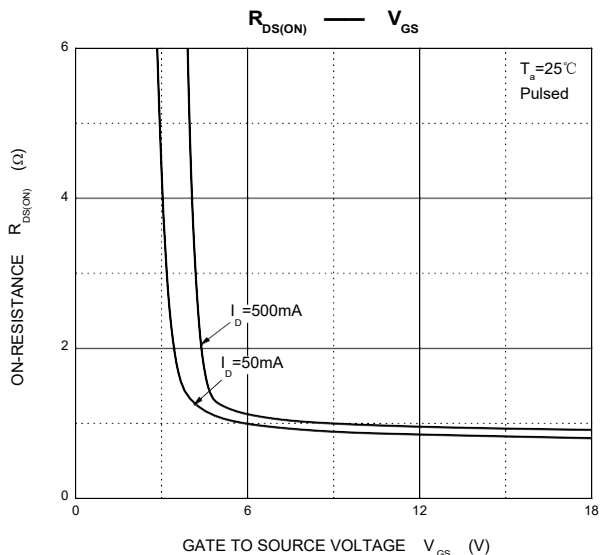
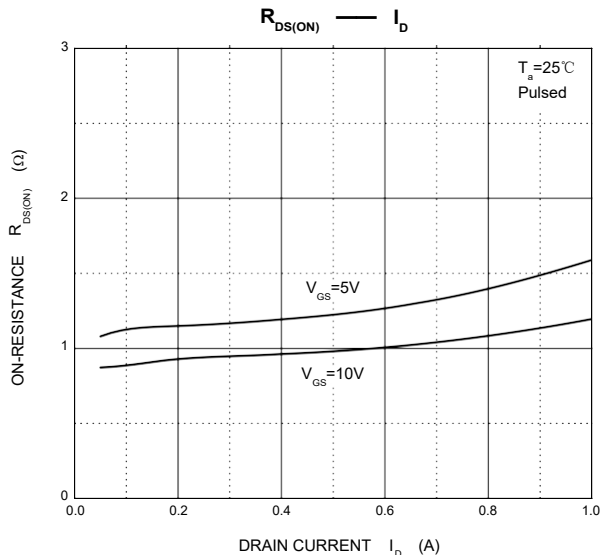
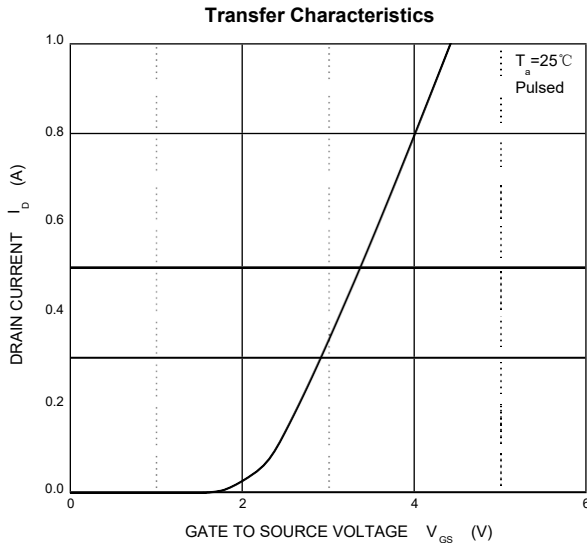
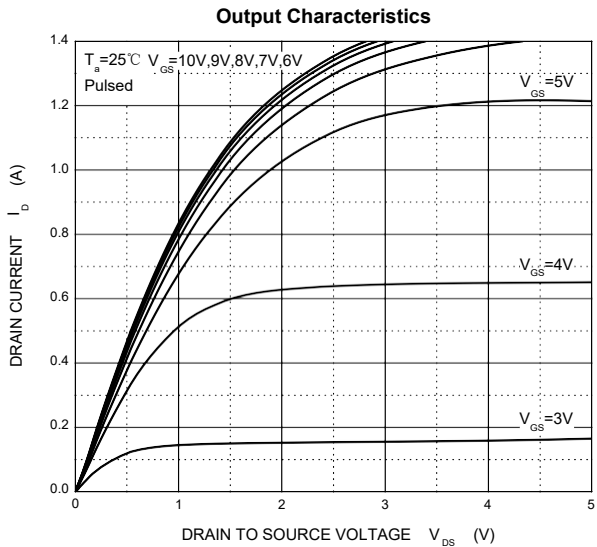
### Absolute Maximum Ratings ( $T_a = 25\text{ °C}$ )

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	60	V
Drain-Gate Voltage ( $R_{GS} \leq 1M\Omega$ )	$V_{DGR}$	60	V
Gate-Source Voltage -Continuous -Non Repetitive ( $t_p < 50\ \mu s$ )	$V_{GSS}$	$\pm 20$ $\pm 40$	V
Maximum Drain Current -Continuous -Pulsed	$I_D$	115 800	mA
Total Power Dissipation	$P_{tot}$	200	mW
Operating and Storage Temperature Range	$T_J, T_s$	- 55 to + 150	$^{\circ}C$

### Characteristics at $T_a = 25\text{ °C}$

Parameter	Symbol	Min.	Max.	Unit
Drain Source Breakdown Voltage at $I_D = 10\ \mu A$	$BV_{DSS}$	60	-	V
Zero Gate Voltage Drain Current at $V_{DS} = 60\ V$	$I_{DSS}$	-	1	$\mu A$
Gate-Body Leakage Current at $V_{GS} = \pm 20\ V$	$\pm I_{GSS}$	-	100	nA
Gate Threshold Voltage at $V_{DS} = V_{GS}, I_D = 250\ \mu A$	$V_{GS(th)}$	1	2.5	V
On-State Drain Current at $V_{GS} = 10\ V, V_{DS} = 7.5\ V$	$I_{D(ON)}$	500	-	mA
Drain-Source On-Voltage at $V_{GS} = 10\ V, I_D = 500\ mA$ at $V_{GS} = 5\ V, I_D = 50\ mA$	$V_{DS(ON)}$	- -	3.75 1.5	V V
Static Drain-Source On-Resistance at $V_{GS} = 10\ V, I_D = 500\ mA$	$R_{DS(ON)}$	-	7.5	$\Omega$
Forward Transconductance at $V_{DS} = 10\ V, I_D = 200\ mA$	$g_{FS}$	80	-	mS
Input Capacitance at $V_{DS} = 25\ V, f = 1\ MHz$	$C_{iss}$	-	50	pF
Output Capacitance at $V_{DS} = 25\ V, f = 1\ MHz$	$C_{oss}$	-	25	pF
Reverse Transfer Capacitance at $V_{DS} = 25\ V, f = 1\ MHz$	$C_{rss}$	-	5	pF
Turn-On Time at $V_{DD} = 30\ V, R_L = 150\ \Omega, I_D = 0.2\ A, V_{GS} = 10V, R_{GEN} = 25\ \Omega$	$t_{on}$	-	20	ns
Turn-Off Time at $V_{DD} = 30\ V, R_L = 150\ \Omega, I_D = 0.2\ A, V_{GS} = 10V, R_{GEN} = 25\ \Omega$	$t_{off}$	-	20	ns

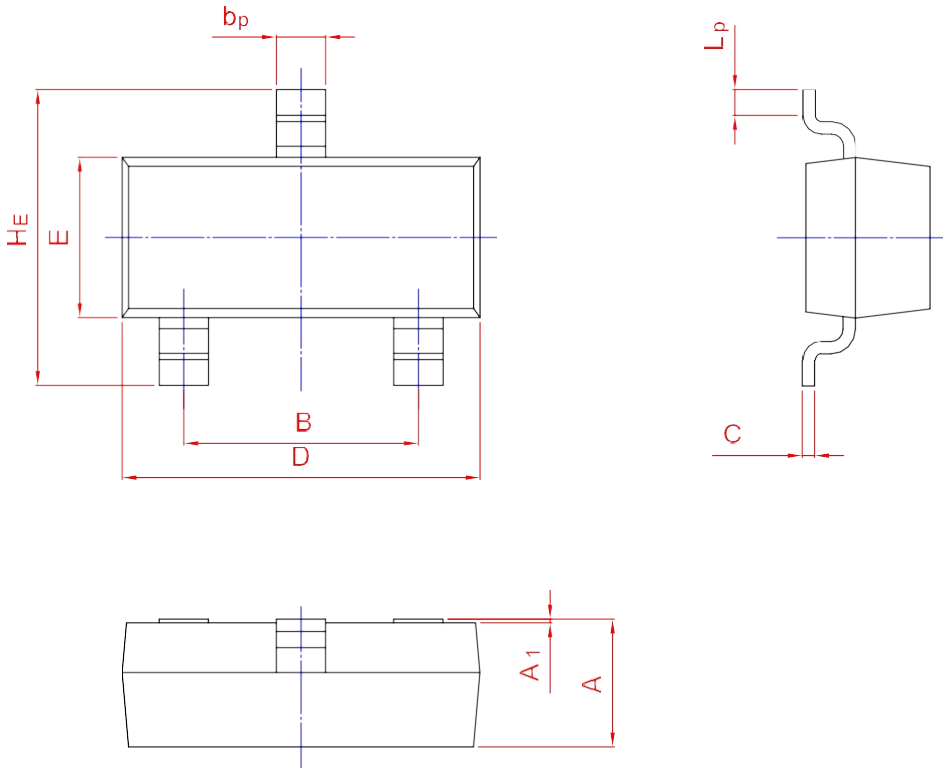
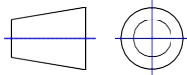
Typical Characteristics



PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



UNIT	A	B	b <sub>p</sub>	C	D	E	H <sub>E</sub>	A <sub>1</sub>	L <sub>p</sub>
mm	1.40	2.04	0.50	0.19	3.10	1.65	3.00	0.100	0.50
	0.95	1.78	0.35	0.08	2.70	1.20	2.20	0.013	0.20